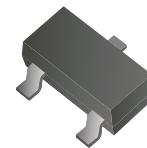


CJ2301-HF

**P-Channel
RoHS Device
Halogen Free**



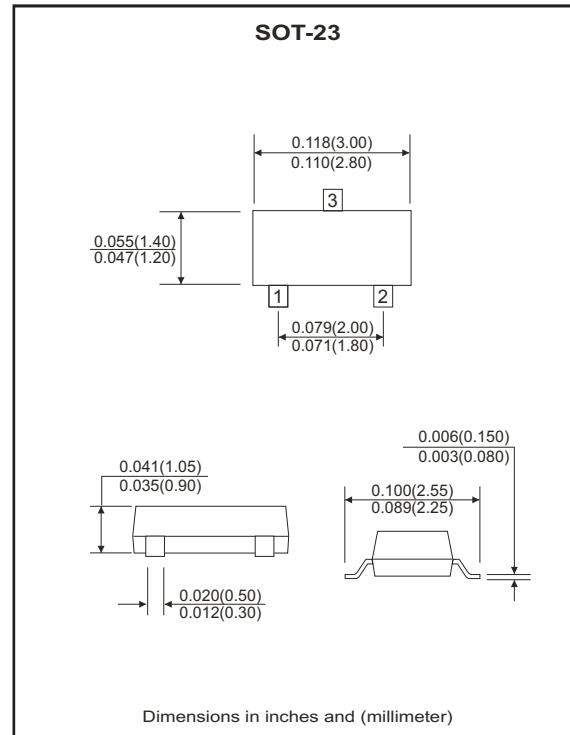
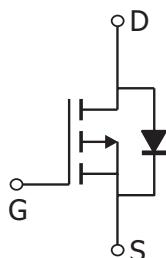
Features

- P-Channel 20-V(D-S) MOSFET
- Trench FET Power MOSFET.
- Load Switch for Portable Devices.
- DC/DC Converter.

Mechanical data

- Case: SOT-23, molded plastic.
- Terminals: Solderable per MIL-STD-750, method 2026.
- Weight: 0.008 grams(approx.).

Circuit diagram



Dimensions in inches and (millimeter)

Maximum Ratings and Electrical Characteristics

(at Ta=25 °C unless otherwise noted)

Parameter	Symbol	Value	Units
Drain-source voltage	V _{DS}	-20	V
Gate-source voltage	V _{GS}	±8	V
Continuous drain current	I _D	-2.3	A
Pulsed drain current	I _{DM}	-10	
Continuous source-drain diode current	I _S	-0.72	
Maximum power dissipation	P _D	350	mW
Thermal resistance from junction to ambient (t≤5s)	R _{θJA}	357	°C/W
Junction temperature range	T _J	150	°C
Storage temperature range	T _{STG}	-55 to +150	°C

Company reserves the right to improve product design , functions and reliability without notice.

REV:A

Electrical Characteristics (at TA=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static						
Drain-source breakdown voltage	V(BR) DSS	VGS =0V , ID=-250µA	-20			V
Gate-source threshold voltage	VGS(th)	VDS =VGS , ID=-250µA	-0.4		-1	
Gate-source leakage	IGSS	VDS =0V , VGS=±8V			±100	nA
Zero gate voltage drain current	IDSS	VDS =-20V , VGS=0V			-1	µA
Drain-source on-state resistance (Note a)	RDS(on)	VGS=-4.5V , ID=-2.8A		0.090	0.112	Ω
		VGS=-2.5V , ID=-2.0A		0.110	0.142	
Forward transconductance (Note a)	gfs	VDS=-5V , ID=-2.8A		6.5		S
Dynamic (Note b)						
Input capacitance	Ciss	VDS=-10V , VGS=0V, f=1MHz		405		pF
Output capacitance	Coss			75		
Reverse transfer capacitance	Crss			55		
Total gate charge	Qg	VDS=-10V , VGS=-4.5V, ID=-3A		5.5	10	nC
Gate-soutce charge	Qgs			3.3	6	
Gate-drain charge	Qgd			0.7		
Gate resistance	Rg		f=1MHz	1.3		
Turn-on delay time	td(on)	VDD=-10V , RL=10Ω , ID=-1A VGEN=-4.5V Rg=1Ω		6.0		Ω
Rise time	tr			11	20	nS
Turn-off delay time	td(off)			35	60	
Fall time	tf			30	50	
				10	20	
Drain-source body diode characteristics						
Continuous souce-drain diode current	Is	Tc=25°C			-1.3	A
Pulse diode forward current (Note a)	ISM				-10	
Body diode voltage	VSD	Is=-0.7A		-0.8	-1.2	V

Notes:

- a. Pulse test: Pulse width <300µs, Duty cycle ≤ 2%
- b. Guaranteed by design, not subject to production testing.

RATING AND CHARACTERISTIC CURVES (CJ2301-HF)

Fig.1 - Output Characteristics

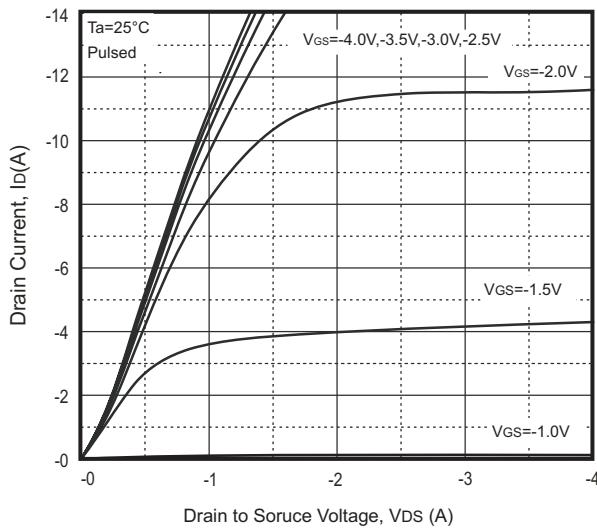


Fig.2 - Transfer Characteristics

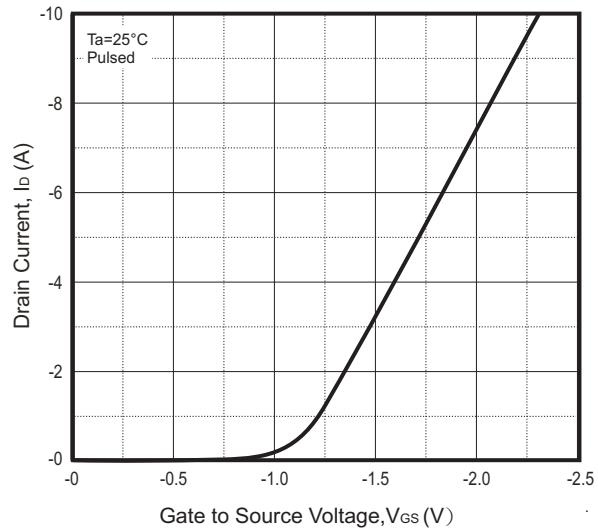


Fig.3 - $R_{DS(ON)}$ — I_D

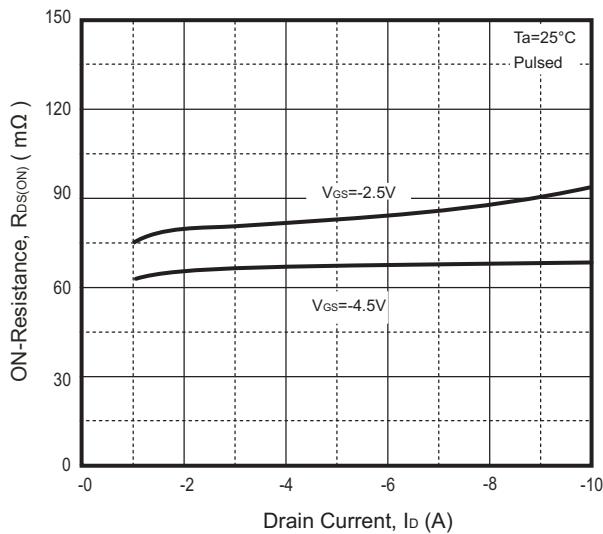


Fig.4 - $R_{DS(ON)}$ — V_{GS}

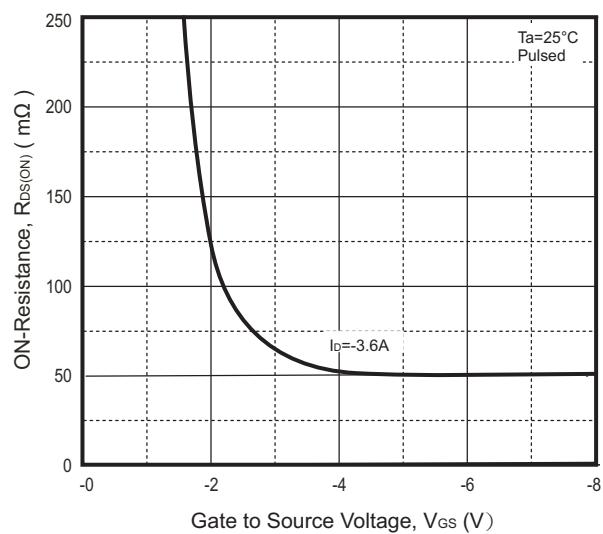
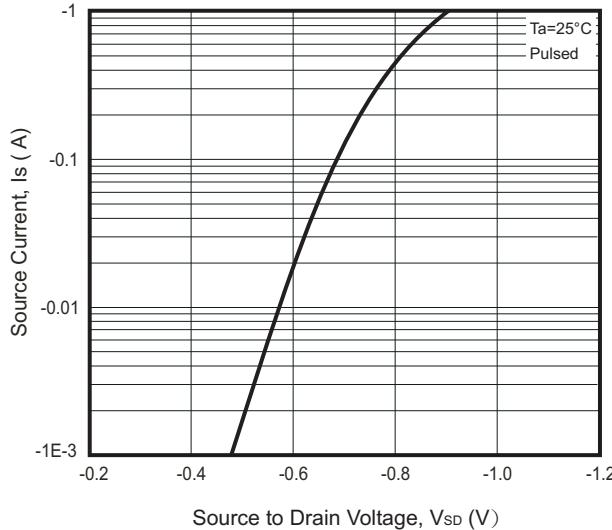
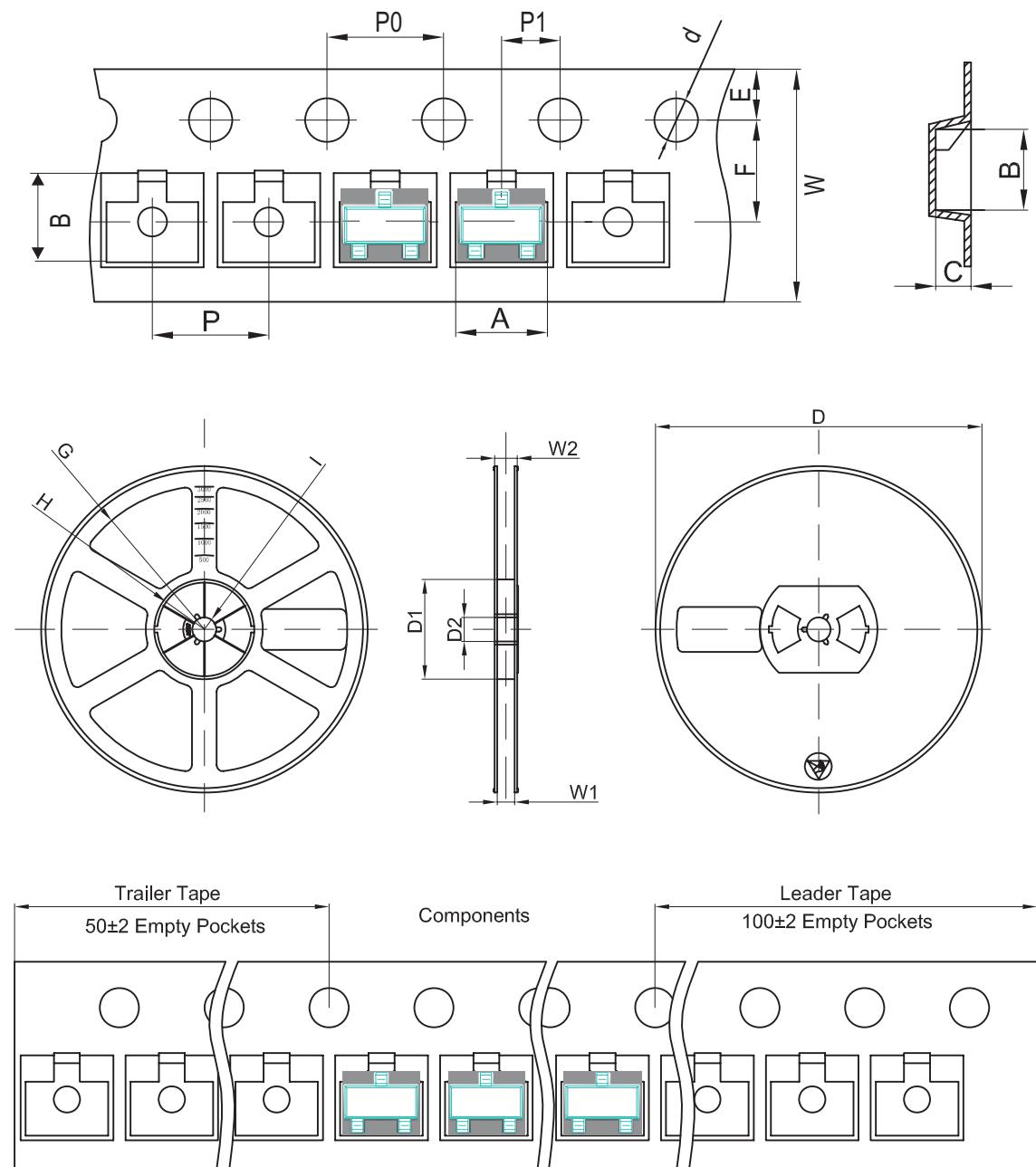


Fig.5 - I_S — V_{SD}



Company reserves the right to improve product design , functions and reliability without notice.

Reel Taping Specification



SOT-23	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	3.15 ± 0.10	2.77 ± 0.10	1.22 ± 0.10	1.50 ± 0.10	178 ± 2.0	54.40 ± 1.0	13.00 ± 1.0
	(inch)	0.124 ± 0.004	0.109 ± 0.004	0.048 ± 0.004	0.059 ± 0.004	7.008 ± 0.079	2.142 ± 0.039	0.512 ± 0.039

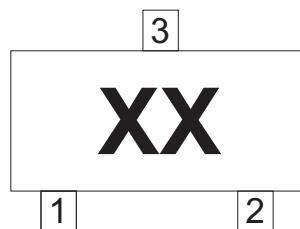
SOT-23	SYMBOL	E	F	P	P0	P1	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	$8.00 + 0.30 / - 0.10$	9.50 ± 1.00
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.158 ± 0.004	0.158 ± 0.004	0.079 ± 0.004	$0.315 + 0.012 / - 0.004$	0.374 ± 0.039

Company reserves the right to improve product design , functions and reliability without notice.

REV:A

Marking Code

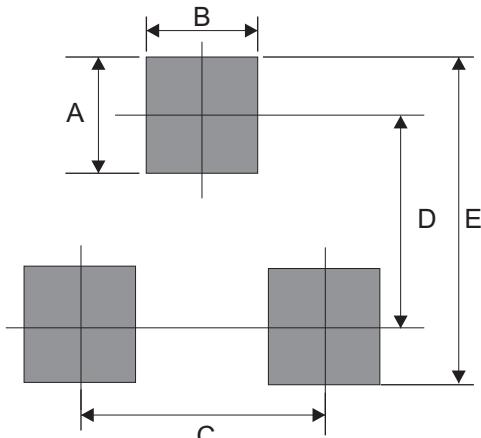
Part Number	Marking Code
CJ2301-HF	S1



xx = Product type marking code

Suggested PAD Layout

SIZE	SOT-23	
	(mm)	(inch)
A	0.80	0.031
B	0.80	0.031
C	1.90	0.075
D	2.02	0.080
E	2.82	0.111



Standard Packaging

Case Type	Qty Per Reel	Reel Size
	(Pcs)	(inch)
SOT-23	3,000	7